



# 670MHz LVDS-to-LVDS and Anything-to-LVDS 1:2 Splitters

MAX9174/MAX9175

## General Description

The MAX9174/MAX9175 are 670MHz, low-jitter, low-skew 1:2 splitters ideal for protection switching, loopback, and clock and signal distribution. The devices feature ultra-low 1.0ps(RMS) random jitter (max) that ensures reliable operation in high-speed links that are highly sensitive to timing errors.

The MAX9174 has a fail-safe LVDS input and LVDS outputs. The MAX9175 has an anything differential input (CML/LVDS/LVPECL) and LVDS outputs. The outputs can be put into high impedance using the power-down inputs. The MAX9174 features a fail-safe circuit that drives the outputs high when the input is open, undriven and shorted, or undriven and terminated. The MAX9175 has a bias circuit that forces the outputs high when the input is open. The power-down inputs are compatible with standard LVTTTL/LVCMOS logic. The power-down inputs tolerate undershoot of -1V and overshoot of  $V_{CC} + 1V$ . The MAX9174/MAX9175 are available in 10-pin  $\mu$ MAX and 10-lead thin QFN with exposed pad packages, and operate from a single +3.3V supply over the -40°C to +85°C temperature range.

## Applications

- Protection Switching
- Loopback
- Clock Distribution

**Functional Diagram and Pin Configurations appear at end of data sheet.**

## Features

- ◆ 1.0ps(RMS) Jitter (max) at 670MHz
- ◆ 80ps(p-p) Jitter (max) at 800Mbps Data Rate
- ◆ +3.3V Supply
- ◆ LVDS Fail-Safe Inputs (MAX9174)
- ◆ Anything Input (MAX9175) Accepts Differential CML/LVDS/LVPECL
- ◆ Power-Down Inputs Tolerate -1.0V and  $V_{CC} + 1.0V$
- ◆ Low-Power CMOS Design
- ◆ 10-Lead  $\mu$ MAX and Thin QFN Packages
- ◆ -40°C to +85°C Operating Temperature Range
- ◆ Conform to ANSI TIA/EIA-644 LVDS Standard
- ◆ IEC 61000-4-2 Level 4 ESD Rating

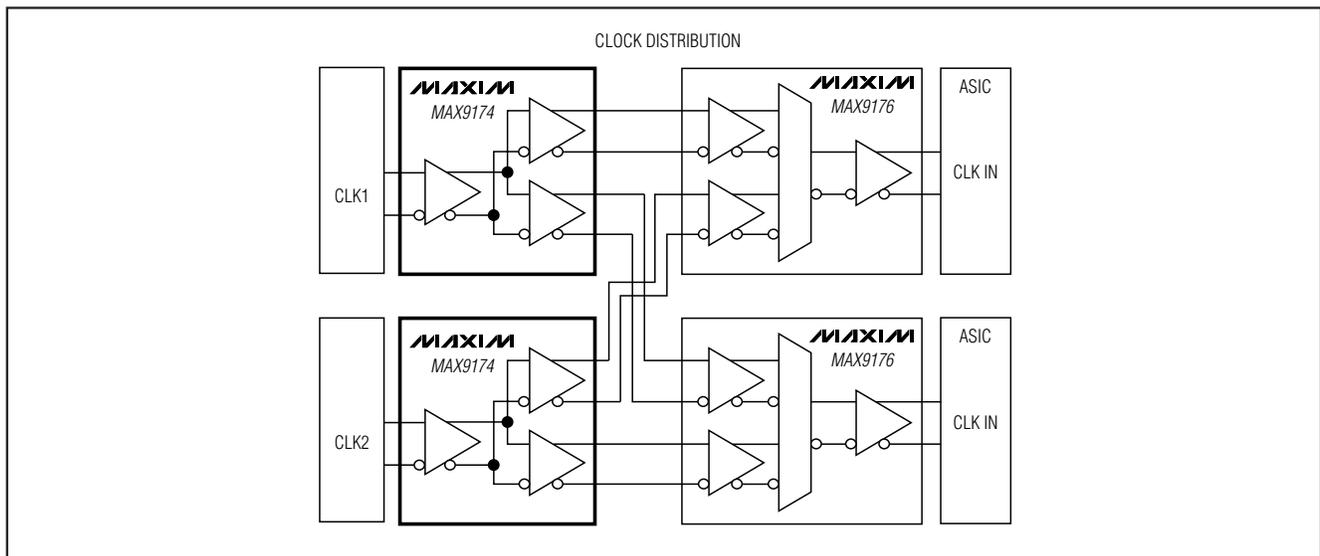
## Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX9174EUB	-40°C to +85°C	10 $\mu$ MAX
MAX9174ETB*	-40°C to +85°C	10 Thin QFN-EP**
MAX9175EUB	-40°C to +85°C	10 $\mu$ MAX
MAX9175ETB*	-40°C to +85°C	10 Thin QFN-EP**

\*Future product—contact factory for availability.

\*\*EP = Exposed paddle.

## Typical Application Circuit



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## ABSOLUTE MAXIMUM RATINGS

V <sub>CC</sub> to GND	-0.3V to +4.0V
IN+, IN- to GND	-0.3V to +4.0V
OUT <sub>+</sub> , OUT <sub>-</sub> to GND	-0.3V to +4.0V
PD0, PD1 to GND	-1.4V to (V <sub>CC</sub> + 1.4V)
Single-Ended and Differential Output	
Short-Circuit Duration (OUT <sub>+</sub> , OUT <sub>-</sub> )	Continuous
Continuous Power Dissipation (T <sub>A</sub> = +70°C)	
10-Pin μMAX (derate 5.6mW/°C above +70°C)	444mW
10-Lead QFN (derate 24.4mW/°C above +70°C)	1951mW
Maximum Junction Temperature	+150°C

Storage Temperature Range	-65°C to +150°C
ESD Protection	
Human Body Model (R <sub>D</sub> = 1.5kΩ, C <sub>S</sub> = 100pF)	
IN+, IN-, OUT <sub>+</sub> , OUT <sub>-</sub>	±2kV
Other Pins (V <sub>CC</sub> , PD0, PD1)	±2kV
IEC 61000-4-2 Level 4 (R <sub>D</sub> = 330Ω, C <sub>S</sub> = 150pF)	
Contact Discharge IN+, IN-, OUT <sub>+</sub> , OUT <sub>-</sub>	±8kV
Air-Gap Discharge IN+, IN-, OUT <sub>+</sub> , OUT <sub>-</sub>	±15kV
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS

(V<sub>CC</sub> = +3.0V to +3.6V, R<sub>L</sub> = 100Ω ±1%,  $\overline{PD}$  = high, differential input voltage |V<sub>ID</sub>| = 0.05V to 1.2V, MAX9174 input common-mode voltage V<sub>CM</sub> = |V<sub>ID</sub> / 2| to (2.4V - |V<sub>ID</sub> / 2|), MAX9175 input common-mode voltage V<sub>CM</sub> = |V<sub>ID</sub> / 2| to (V<sub>CC</sub> - |V<sub>ID</sub> / 2|), T<sub>A</sub> = -40°C to +85°C, unless otherwise noted. Typical values are at V<sub>CC</sub> = +3.3V, |V<sub>ID</sub>| = 0.2V, V<sub>CM</sub> = +1.25V, T<sub>A</sub> = +25°C.) (Notes 1, 2, 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
<b>DIFFERENTIAL INPUT (IN+, IN-)</b>						
Differential Input High Threshold	V <sub>TH</sub>				+50	mV
Differential Input Low Threshold	V <sub>TL</sub>		-50			mV
Input Current	I <sub>IN+</sub> , I <sub>IN-</sub>	Figure 1	-20		+20	μA
Power-Off Input Current	I <sub>IN+</sub> , I <sub>IN-</sub>	MAX9174 V <sub>CC</sub> = 0V or open, Figure 1 MAX9175 V <sub>IN+</sub> = 3.6V or 0V, V <sub>IN-</sub> = 3.6V or 0V, V <sub>CC</sub> = 0V or open, Figure 1	-20		+20	μA
Fail-Safe Input Resistors (MAX9174)	R <sub>IN1</sub> R <sub>IN2</sub>	V <sub>CC</sub> = 3.6V, 0V or open, Figure 1	60		108	kΩ
Input Resistors (MAX9175)	R <sub>IN3</sub>	V <sub>CC</sub> = 3.6V, 0V or open, Figure 1	212		450	kΩ
Input Capacitance	C <sub>IN</sub>	IN+ or IN- to GND (Note 4)			4.5	pF
<b>LVTTTL/LVCMOS INPUTS (PD0, PD1)</b>						
Input High Voltage	V <sub>IH</sub>		2.0		V <sub>CC</sub> + 1	V
Input Low Voltage	V <sub>IL</sub>		-1.0		+0.8	V
Input Current	I <sub>IN</sub>	-1.0V ≤ $\overline{PD}$ ≤ 0V	-1.5			mA
		0V ≤ $\overline{PD}$ ≤ V <sub>CC</sub>	-20		+20	μA
		V <sub>CC</sub> ≤ $\overline{PD}$ ≤ V <sub>CC</sub> + 1.0V			+1.5	mA
<b>LVDS OUTPUTS (OUT<sub>+</sub>, OUT<sub>-</sub>)</b>						
Differential Output Voltage	V <sub>OD</sub>	Figure 2	250	393	475	mV
Change in Differential Output Voltage Between Logic States	ΔV <sub>OD</sub>	Figure 2		1.0	15	mV
Offset Voltage	V <sub>OS</sub>	Figure 3	1.125	1.29	1.375	V

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MAX9174/MAX9175

## DC ELECTRICAL CHARACTERISTICS (continued)

( $V_{CC} = +3.0V$  to  $+3.6V$ ,  $R_L = 100\Omega \pm 1\%$ ,  $\overline{PD}_- = \text{high}$ , differential input voltage  $|V_{ID}| = 0.05V$  to  $1.2V$ , MAX9174 input common-mode voltage  $V_{CM} = |V_{ID}|/2$  to  $(2.4V - |V_{ID}|/2)$ , MAX9175 input common-mode voltage  $V_{CM} = |V_{ID}|/2$  to  $(V_{CC} - |V_{ID}|/2)$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ , unless otherwise noted. Typical values are at  $V_{CC} = +3.3V$ ,  $|V_{ID}| = 0.2V$ ,  $V_{CM} = +1.25V$ ,  $T_A = +25^\circ C$ .) (Notes 1, 2, 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Change in Offset Voltage Between Logic States	$\Delta V_{OS}$	Figure 3		1.0	15	mV
Fail-Safe Differential Output Voltage (MAX9174)	$V_{OD}$	Figure 2	250	393	475	mV
Differential Output Resistance	$R_{DIFF}$	$V_{CC} = 3.6V$ or $0V$	86	119	160	$\Omega$
Power-Down Single-Ended Output Current	$I_{PD}$	$\overline{PD}_- = \text{low}$ $V_{OUT\_+} = \text{open},$ $V_{OUT\_+} = 3.6V$ or $0V$ $V_{OUT\_+} = \text{open},$ $V_{OUT\_+} = 3.6V$ or $0V$	-1.0	$\pm 0.03$	+1.0	$\mu A$
Power-Off Single-Ended Output Current	$I_{OFF}$	$\overline{PD}_0, \overline{PD}_1 = \text{low},$ $V_{CC} = 0V$ or open $V_{OUT\_+} = \text{open},$ $V_{OUT\_+} = 3.6V$ or $0V$ $V_{OUT\_+} = \text{open},$ $V_{OUT\_+} = 3.6V$ or $0V$	-1.0	$\pm 0.03$	+1.0	$\mu A$
Output Short-Circuit Current	$I_{OS}$	$V_{ID} = +50mV$ or $-50mV$ , $V_{OUT\_+} = 0V$ or $V_{CC}$ $V_{ID} = +50mV$ or $-50mV$ , $V_{OUT\_+} = 0V$ or $V_{CC}$	-15		+15	mA
Differential Output Short-Circuit Current Magnitude	$ I_{OSD} $	$V_{ID} = +50mV$ or $-50mV$ , $V_{OD} = 0V$ (Note 4)			15	mA
Supply Current	$I_{CC}$	$\overline{PD}_0 = V_{CC}, \overline{PD}_1 = 0V$ or $\overline{PD}_0 = 0V, \overline{PD}_1 = V_{CC}$ $\overline{PD}_0 = V_{CC}, \overline{PD}_1 = V_{CC}$		17 25	26 35	mA
Power-Down Supply Current	$I_{CCPD}$	$\overline{PD}_1, \overline{PD}_0 = 0V$		0.5	20	$\mu A$
Output Capacitance	$C_O$	$OUT\_+$ or $OUT_-$ to GND (Note 4)			5.2	pF

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## AC ELECTRICAL CHARACTERISTICS

( $V_{CC} = +3.0V$  to  $+3.6V$ ,  $R_L = 100\Omega \pm 1\%$ ,  $C_L = 5pF$ , differential input voltage  $|V_{ID}| = 0.15V$  to  $1.2V$ , MAX9174 input common-mode voltage,  $V_{CM} = |V_{ID}|/2$  to  $(2.4V - |V_{ID}|/2)$ , MAX9175 input common-mode voltage  $V_{CM} = |V_{ID}|/2$  to  $(V_{CC} - |V_{ID}|/2)$ ,  $\overline{PD}_- = \text{high}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ , unless otherwise noted. Typical values are at  $V_{CC} = +3.3V$ ,  $|V_{ID}| = 0.2V$ ,  $V_{CM} = +1.25V$ ,  $T_A = +25^\circ\text{C}$ .) (Notes 5, 6, 7)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
High-to-Low Propagation Delay	$t_{PHL}$	Figures 4, 5	1.33	2.38	3.23	ns
Low-to-High Propagation Delay	$t_{PLH}$	Figures 4, 5	1.33	2.39	3.23	ns
Added Deterministic Jitter	$t_{DJ}$	Figures 4, 5 (Note 8)			80	ps(P-P)
Added Random Jitter	$t_{RJ}$	Figures 4, 5			1.0	ps(RMS)
Pulse Skew $ t_{PLH} - t_{PHL} $	$t_{SKP}$	Figures 4, 5		10	141	ps
Output-to-Output Skew	$t_{SKOO}$	Figure 6		14	45	ps
Part-to-Part Skew	$t_{SKPP1}$	Figures 4, 5 (Note 9)		0.4	1.3	ns
	$t_{SKPP2}$	Figures 4, 5 (Note 10)			1.9	
Rise Time	$t_R$	Figures 4, 5	110	257	365	ps
Fall Time	$t_F$	Figures 4, 5	110	252	365	ps
Power-Down Time	$t_{PD}$	Figures 7, 8		10	13	ns
Power-Up Time	$t_{PU}$	$\overline{PD0}, \overline{PD1} = L \rightarrow H$ , Figures 7, 8		18	35	$\mu\text{s}$
		$\overline{PD0} = H, \overline{PD1} = L \rightarrow H$ , Figures 7, 8		92	103	ns
		$\overline{PD1} = H, \overline{PD0} = L \rightarrow H$ , Figures 7, 8		92	103	
Maximum Data Rate	$D_{RMAX}$	Figures 4, 5, $ V_{OD}  \geq 250\text{mV}$ (Note 11)	800			Mbps
Maximum Switching Frequency	$f_{MAX}$	Figures 4, 5, $ V_{OD}  \geq 250\text{mV}$ (Note 11)	670			MHz
Switching Supply Current	$I_{CCSW}$	$f_{IN} = 670\text{MHz}$		55	65	mA
		$f_{IN} = 155\text{MHz}$		35	44	
PRBS Supply Current	$I_{CCPR}$	$D_R = 800\text{Mbps}$ , $2^{23} - 1$ PRBS input		37	46	mA

**Note 1:** Current into a pin is defined as positive. Current out of a pin is defined as negative. All voltages are referenced to ground except  $V_{TH}$ ,  $V_{TL}$ ,  $V_{ID}$ ,  $V_{OD}$ , and  $\Delta V_{OD}$ .

**Note 2:** Maximum and minimum limits over temperature are guaranteed by design and characterization. Devices are 100% tested at  $T_A = +25^\circ\text{C}$ .

**Note 3:** Tolerance on all external resistors (including figures) is  $\pm 1\%$ .

**Note 4:** Guaranteed by design.

**Note 5:** AC parameters are guaranteed by design and characterization and are not production tested. Limits are set at  $\pm 6$  sigma.

**Note 6:**  $C_L$  includes scope probe and test jig capacitance.

**Note 7:** Pulse-generator output for differential inputs  $IN+$ ,  $IN-$  (unless otherwise noted):  $f = 670\text{MHz}$ , 50% duty cycle,  $R_O = 50\Omega$ ,  $t_R = 700\text{ps}$ , and  $t_F = 700\text{ps}$  (0% to 100%). Pulse-generator output for single-ended inputs  $\overline{PD0}$ ,  $\overline{PD1}$ :  $t_R = t_F = 1.5\text{ns}$  ( $0.2V_{CC}$  to  $0.8V_{CC}$ ), 50% duty cycle,  $V_{OH} = V_{CC} + 1.0V$  settling to  $V_{CC}$ ,  $V_{OL} = -1.0V$  settling to zero,  $f = 10\text{kHz}$ .

**Note 8:** Pulse-generator output for  $t_{DJ}$ :  $|V_{OD}| = 0.15V$ ,  $V_{OS} = 1.25V$ , data rate  $800\text{Mbps}$ ,  $2^{23} - 1$  PRBS,  $R_O = 50\Omega$ ,  $t_R = 700\text{ps}$ , and  $t_F = 700\text{ps}$  (0% to 100%).

**Note 9:**  $t_{SKPP1}$  is the magnitude of the difference of any differential propagation delays between devices operating under identical conditions.

**Note 10:**  $t_{SKPP2}$  is the magnitude of the difference of any differential propagation delays between devices operating over rated conditions.

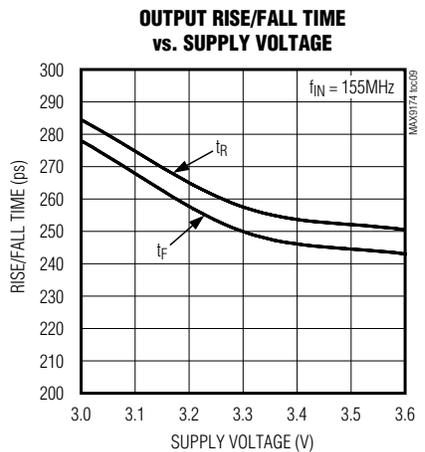
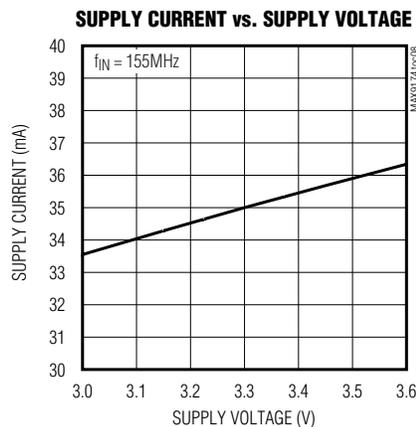
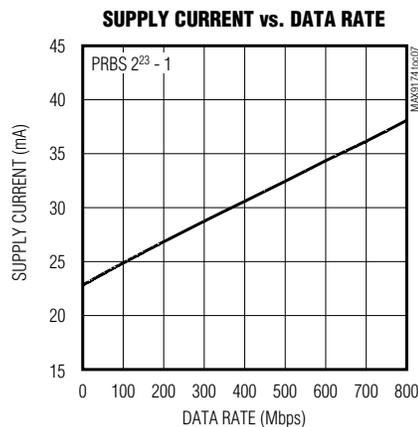
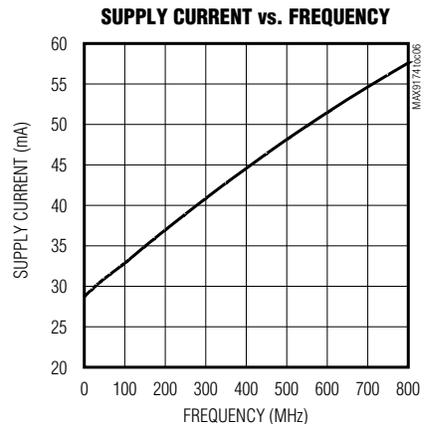
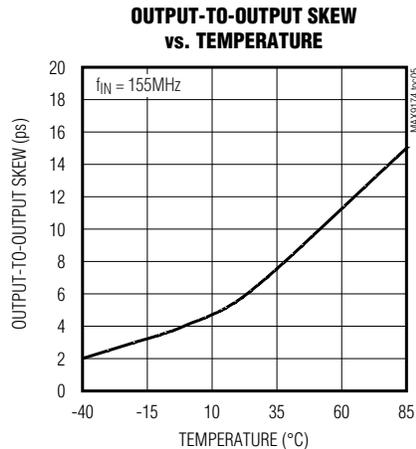
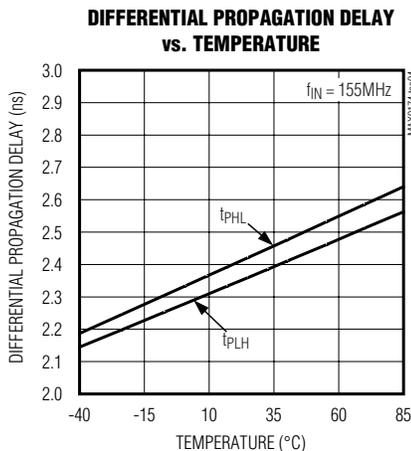
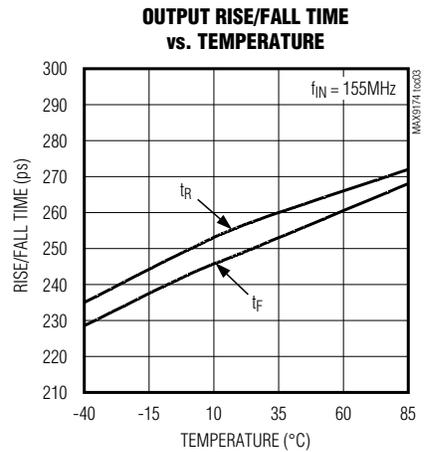
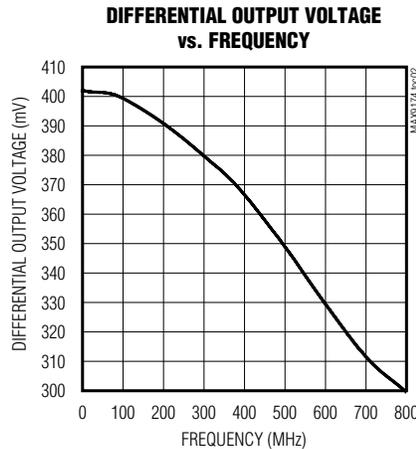
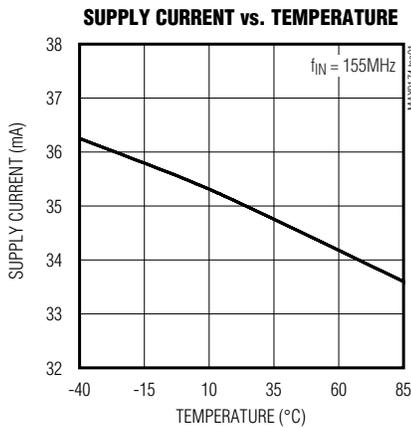
**Note 11:** Meets all AC specifications.

# 670MHz LVDS-to-LVDS and Anything-to-LVDS 1:2 Splitters

## Typical Operating Characteristics

((MAX9174)  $V_{CC} = +3.3V$ ,  $|V_{ID}| = 0.15V$ ,  $V_{CM} = 1.25V$ ,  $T_A = +25^\circ C$ ,  $R_L = 100\Omega \pm 1\%$ ,  $C_L = 5pf$ ,  $\overline{PD}_- = V_{CC}$ , unless otherwise noted.)

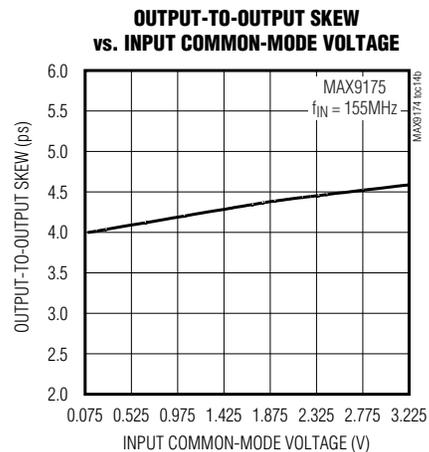
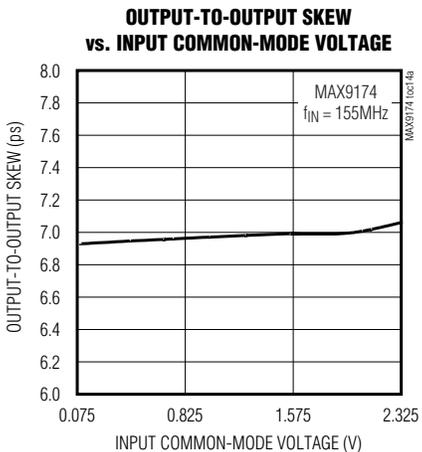
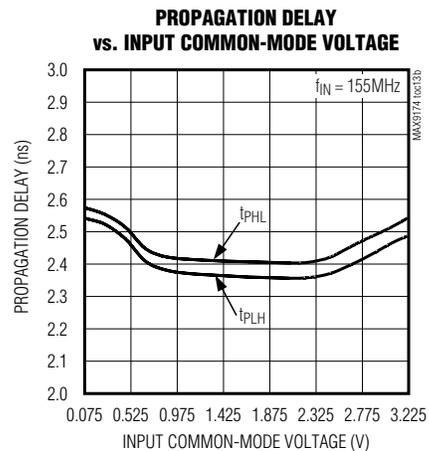
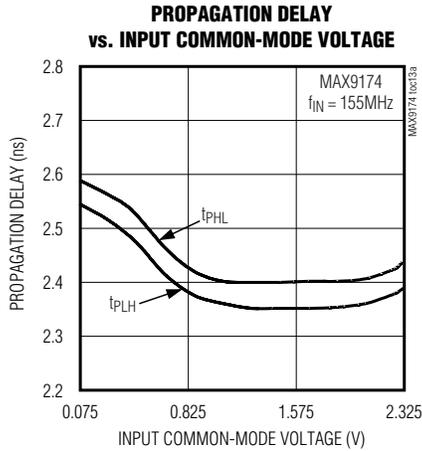
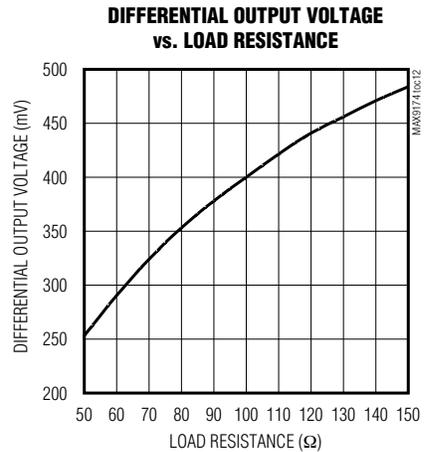
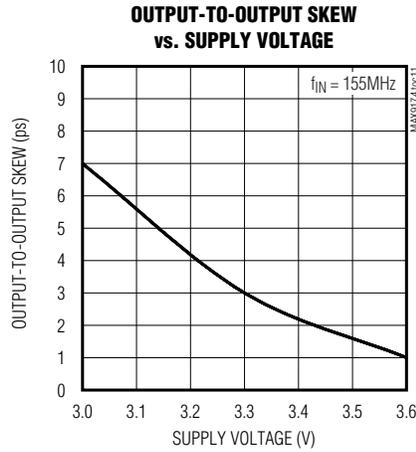
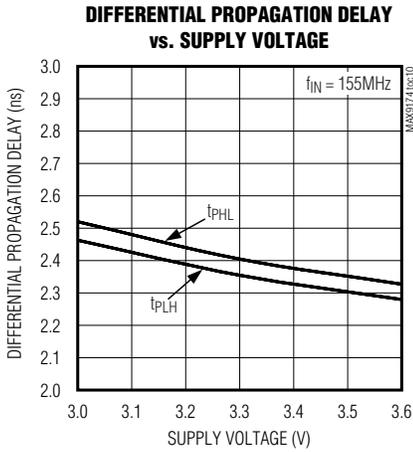
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# 670MHz LVDS-to-LVDS and Anything-to-LVDS 1:2 Splitters

## Typical Operating Characteristics (continued)

((MAX9174)  $V_{CC} = +3.3V$ ,  $|V_{ID}| = 0.15V$ ,  $V_{CM} = 1.25V$ ,  $T_A = +25^\circ C$ ,  $R_L = 100\Omega \pm 1\%$ ,  $C_L = 5pf$ ,  $\overline{PD}_- = V_{CC}$ , unless otherwise noted.)



# 670MHz LVDS-to-LVDS and Anything-to-LVDS 1:2 Splitters

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## Pin Description

PIN		NAME	FUNCTION
μMAX	QFN		
1	1	IN+	Noninverting Differential Input
2	2	IN-	Inverting Differential Input
3	3	GND	Ground
4	4	$\overline{\text{PD1}}$	LVTTTL/LVCMOS Input. OUT1+, OUT1- are high impedance to ground when $\overline{\text{PD1}}$ is low. Internal pulldown resistor to GND.
5	5	$\overline{\text{PD0}}$	LVTTTL/LVCMOS Input. OUT0+, OUT0- are high impedance to ground when $\overline{\text{PD0}}$ is low. Internal pulldown resistor to GND.
6	6	OUT0-	Inverting LVDS Output 0
7	7	OUT0+	Noninverting LVDS Output 0
8	8	V <sub>CC</sub>	Power Supply
9	9	OUT1-	Inverting LVDS Output 1
10	10	OUT1+	Noninverting LVDS Output 1
—	EP	Exposed Pad	Exposed Pad. Solder to ground.

## Detailed Description

The MAX9174/MAX9175 are 670MHz, low-jitter, low-skew 1:2 splitters ideal for protection switching, loop-back, and clock and signal distribution. The devices feature ultra-low 80ps<sub>p-p</sub> deterministic jitter (max) that ensures reliable operation in high-speed links that are highly sensitive to timing error.

The MAX9174 has a fail-safe LVDS input and LVDS outputs. The MAX9175 has an anything differential input (CML/LVDS/LVPECL) and LVDS outputs. The outputs can be put into high impedance using the power-down inputs. The MAX9174 features a fail-safe circuit that drives the outputs high when the input is open, undriven and shorted, or undriven and terminated. The MAX9175 has a bias circuit that forces the outputs high when the input is open. The power-down inputs are compatible with standard LVTTTL/LVCMOS logic.

The power-down inputs tolerate undershoot of -1V and overshoot of V<sub>CC</sub> + 1V. The MAX9174/MAX9175 are available in 10-pin μMAX and 10-lead thin QFN packages, and operate from a single +3.3V supply over the -40°C to +85°C temperature range.

### Current-Mode LVDS Outputs

The LVDS outputs use a current-steering configuration. This approach results in less ground bounce and less output ringing, enhancing noise margin and system speed performance.

A differential output voltage is produced by steering current through the parallel combination of the integrated differential output resistor and transmission line impedance/termination resistor. When driving a 100Ω termination resistor, a differential voltage of 250mV to 475mV is produced. For loads greater than 100Ω, the output voltage is larger, and for loads less than 100Ω, the output voltage is smaller. See the Differential Output Voltage vs. Load Resistance curve in *Typical Operating Characteristics* for more information. The outputs are short-circuit current limited for single-ended and differential shorts.

### MAX9174 Input Fail-Safe

The fail-safe feature of the MAX9174 sets the outputs high when the differential input is:

- Open
- Undriven and shorted
- Undriven and terminated

Without a fail-safe circuit, when the input is undriven, noise at the input may switch the outputs and it may appear to the system that data is being sent. Open or undriven terminated input conditions can occur when a cable is disconnected or cut, or when a driver output is in high impedance. A shorted input can occur because of a cable failure.

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When the input is driven with a differential signal of  $|V_{ID}| = 50\text{mV}$  to  $1.2\text{V}$  within a voltage range of 0 to  $2.4\text{V}$ , the fail-safe circuit is not activated. If the input is open, undriven and shorted, or undriven and terminated, an internal resistor in the fail-safe circuit pulls the input above  $V_{CC} - 0.3\text{V}$ , activating the fail-safe circuit and forcing the outputs high (Figure 1).

## Overshoot and Undershoot Voltage Protection

The MAX9174/MAX9175 are designed to protect the power-down inputs (PD0 and PD1) against latchup due to transient overshoot and undershoot voltage. If the input voltage goes above  $V_{CC}$  or below  $GND$  by up to  $1\text{V}$ , an internal circuit limits input current to  $1.5\text{mA}$ .

## Applications Information

### Power-Supply Bypassing

Bypass the  $V_{CC}$  pin with high-frequency surface-mount ceramic  $0.1\mu\text{F}$  and  $0.001\mu\text{F}$  capacitors in parallel as close to the device as possible, with the smaller valued capacitor closest to  $V_{CC}$ .

### Differential Traces

Input and output trace characteristics affect the performance of the MAX9174/MAX9175. Use controlled-impedance differential traces ( $100\Omega$  typ). To reduce radiated noise and ensure that noise couples as common mode, route the differential input and output signals within a pair close together. Reduce skew by matching the electrical length of the two signal paths that make up the differential pair. Excessive skew can result in a degradation of magnetic field cancellation. Maintain a constant distance between the differential traces to avoid discontinuities in differential impedance. Minimize the number of vias to further prevent impedance discontinuities.

### Cables and Connectors

Interconnect for LVDS typically has a controlled differential impedance of  $100\Omega$ . Use cables and connectors that have matched differential impedance to minimize impedance discontinuities.

Avoid the use of unbalanced cables such as ribbon or simple coaxial cable. Balanced cables such as twisted pair offer superior signal quality and tend to generate less EMI due to magnetic field canceling effects. Balanced cables pick up noise as common mode, which is rejected by the LVDS receiver.

### Termination

The MAX9174/MAX9175 require external input and output termination resistors. For LVDS, connect an input

**Table 1. Input Function Table**

INPUT		OUTPUTS
(IN+) - (IN-)		(OUT+) - (OUT-)
$\geq +50\text{mV}$		H
$\leq -50\text{mV}$		L
$-50\text{mV} < V_{ID} < +50\text{mV}$		Indeterminate
MAX9175	Open	H
MAX9174	Open, undriven short, or undriven parallel termination	

**Table 2. Power-Down Function Table**

PD1	PD0	OUT+, OUT-
H	H	Both outputs enabled
L or open	L or open	Shutdown to minimum power, outputs high impedance to ground
L or open	High	OUT0 enabled, OUT1 high impedance to ground
High	L or open	OUT1 enabled, OUT0 high impedance to ground

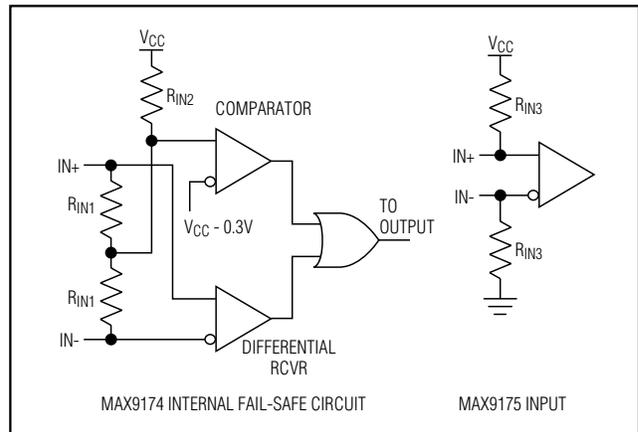


Figure 1. Input Structure

termination resistor across the differential input and at the far end of the interconnect driven by the LVDS outputs. Place the input termination resistor as close to the receiver input as possible. Termination resistors should match the differential impedance of the transmission line. Use 1% surface-mount resistors.

# 670MHz LVDS-to-LVDS and Anything-to-LVDS 1:2 Splitters

MAX9174/MAX9175

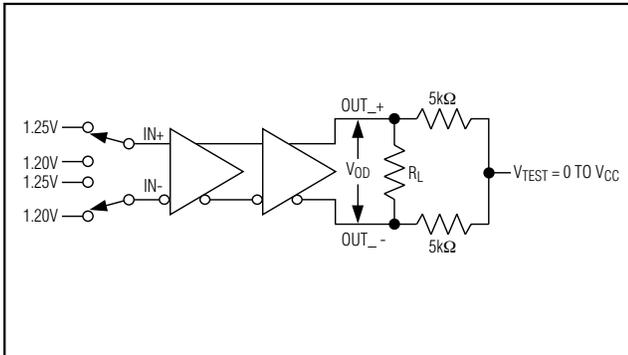


Figure 2.  $V_{OD}$  Test Circuit

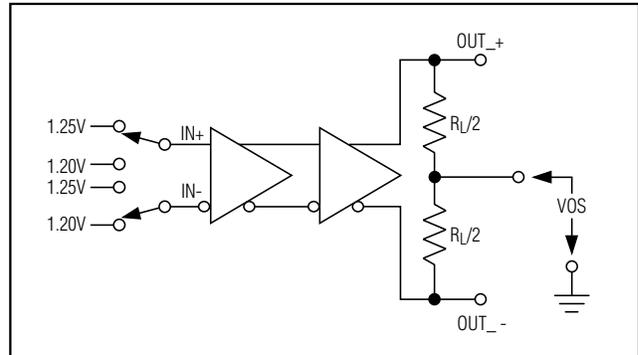


Figure 3.  $V_{OS}$  Test Circuit

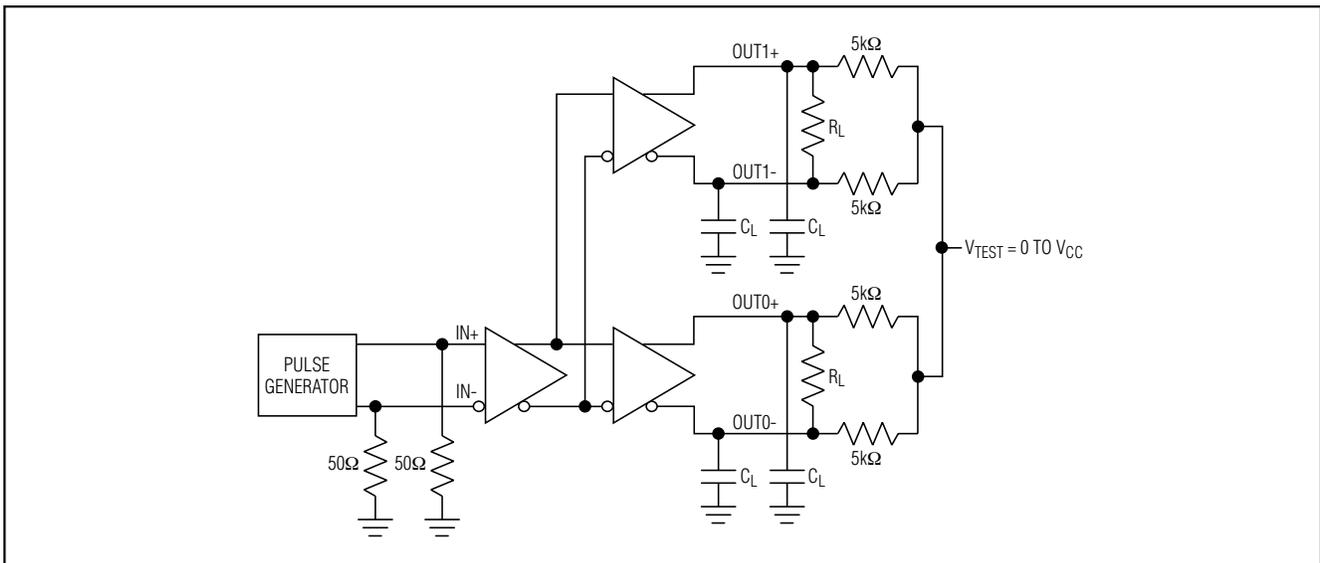


Figure 4. Transition Time, Propagation Delay, and Output-to-Output Skew Test Circuit

The MAX9174/MAX9175 feature an integrated differential output resistor. This resistor reduces jitter by damping reflections produced by a mismatch between the transmission line and termination resistor at the far end of the interconnect.

### Board Layout

Separate the differential and single-ended signals to reduce crosstalk. A four-layer printed circuit board with separate layers for power, ground, differential signals, and single-ended logic signals is recommended. Separate the differential signals from the logic signals with power and ground planes for best results.

### IEC 61000-4-2 Level 4 ESD Protection

The IEC 61000-4-2 standard (Figure 9) specifies ESD tolerance for electronic systems. The IEC 61000-4-2 model specifies a 150pF capacitor that is discharged into the device through a 330Ω resistor. The MAX9174/MAX9175 differential inputs and outputs are rated for IEC 61000-4-2 level 4 ( $\pm 8$ kV Contact Discharge and  $\pm 15$ kV Air-Gap Discharge). The Human Body Model (HBM, Figure 10) specifies a 100pF capacitor that is discharged into the device through a 1.5kΩ resistor. IEC 61000-4-2 level 4 discharges higher peak current and more energy than the HBM due to the lower series resistance and larger capacitor.

# 670MHz LVDS-to-LVDS and Anything-to-LVDS 1:2 Splitters

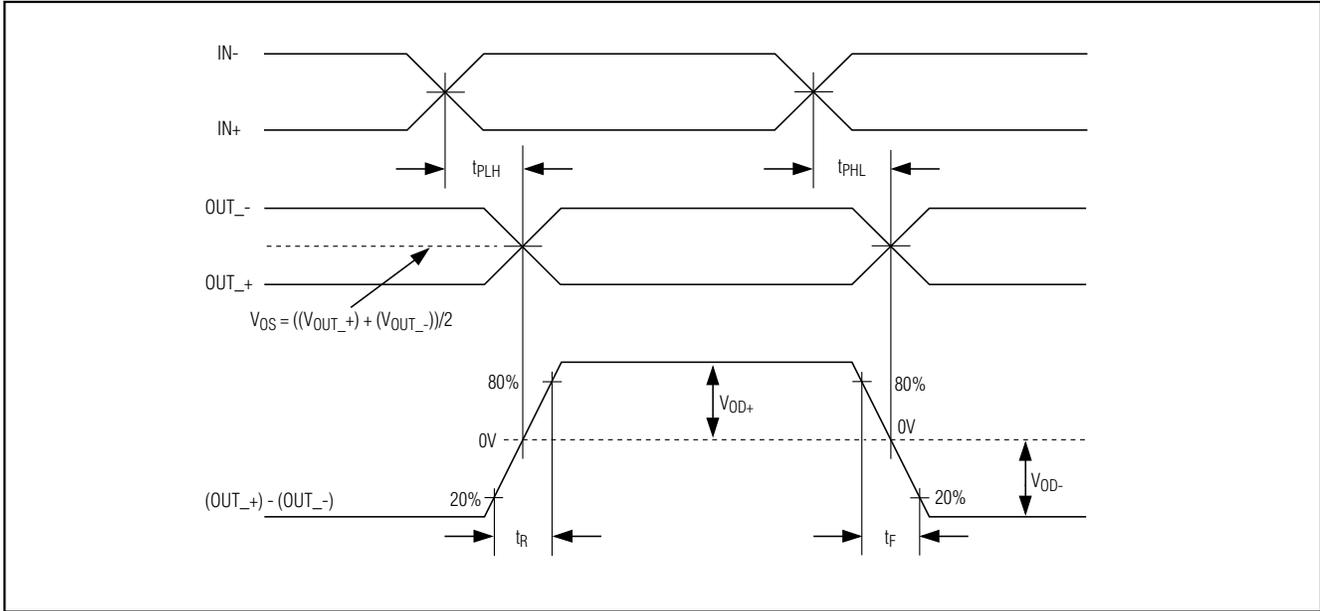


Figure 5. Transition Time and Propagation Delay Timing

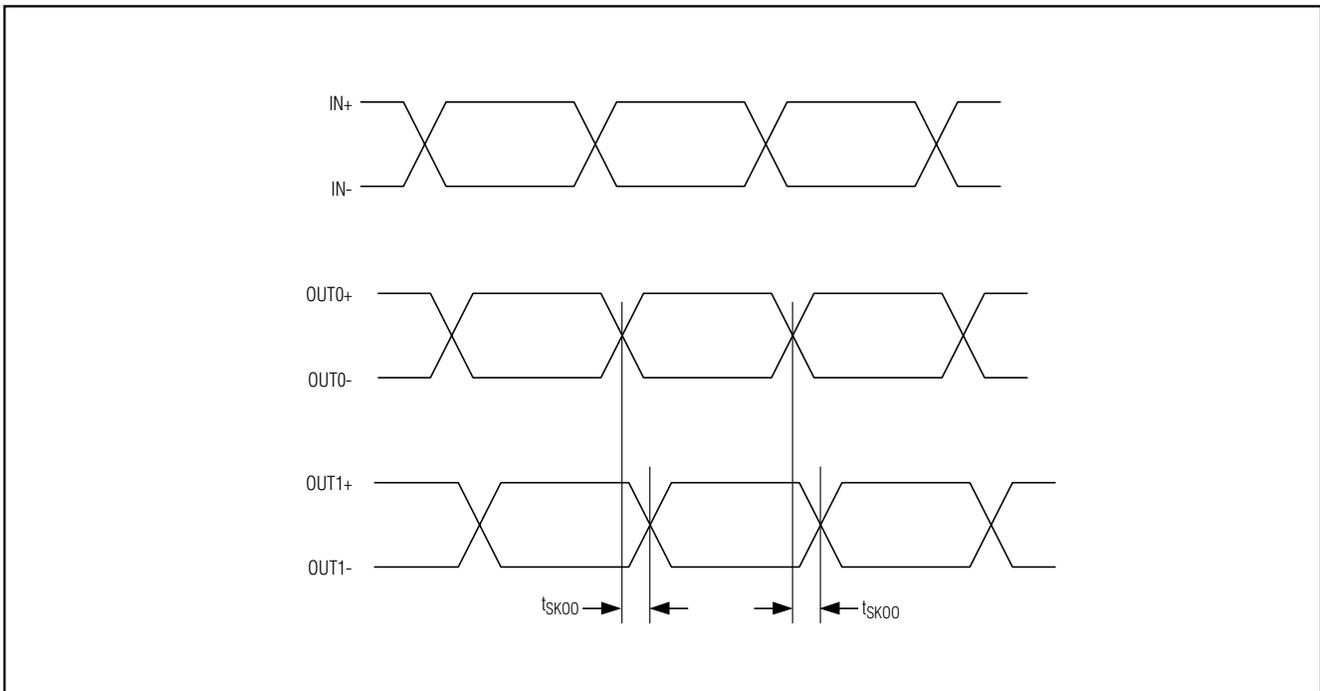


Figure 6. Output-to-Output Skew

# 670MHz LVDS-to-LVDS and Anything-to-LVDS 1:2 Splitters

**MAX9174/MAX9175**

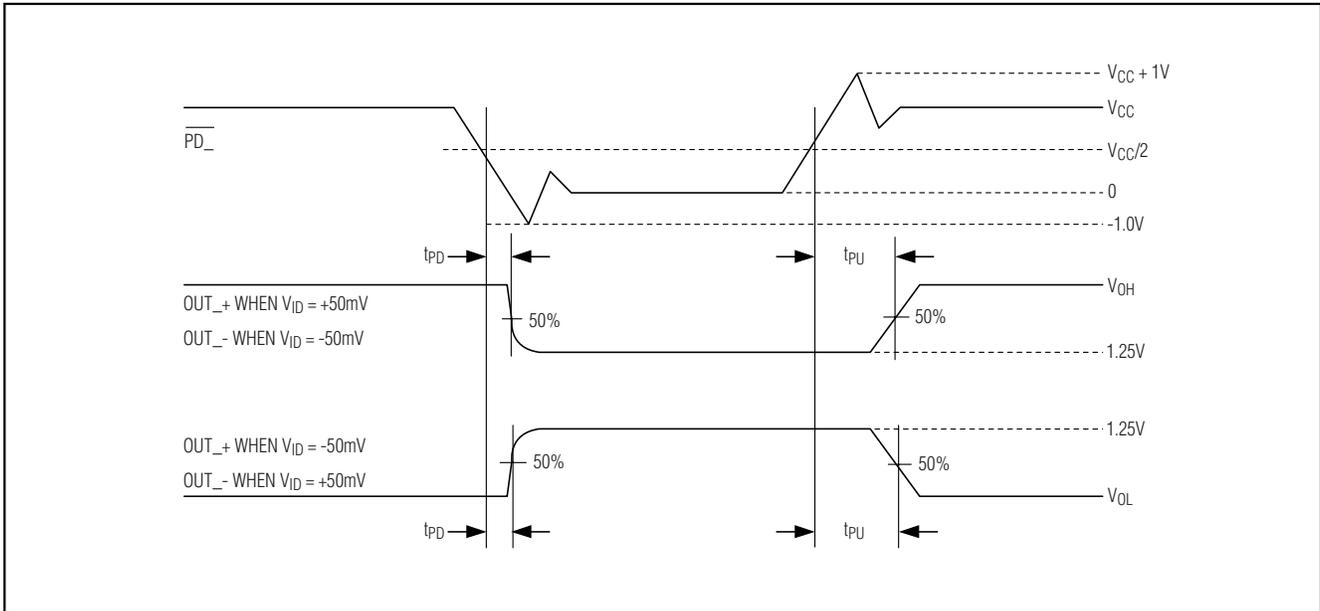


Figure 7. Power-Up/Down Delay Waveform

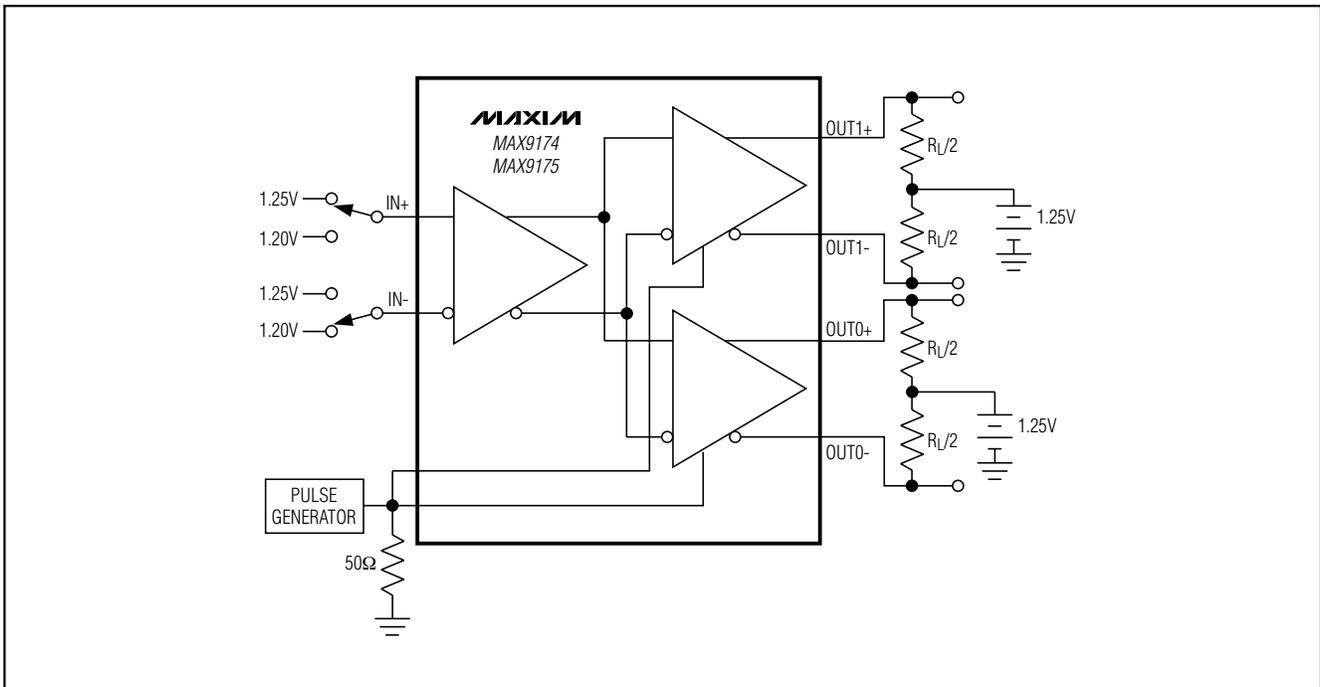


Figure 8. Power-Up/Down Delay Test Circuit

# 670MHz LVDS-to-LVDS and Anything-to-LVDS 1:2 Splitters

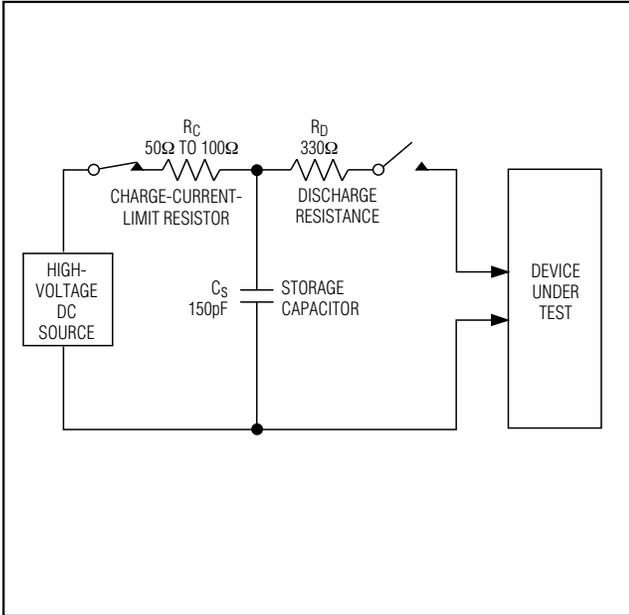


Figure 9. IEC 61000-4-2 Contact Discharge ESD Test Model

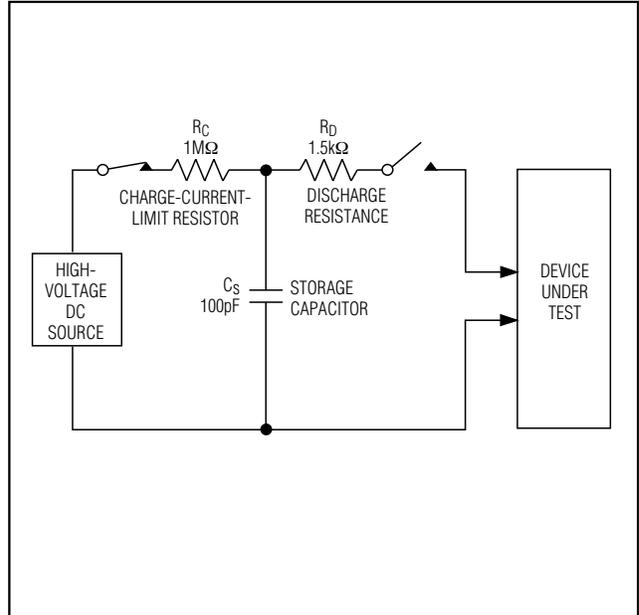
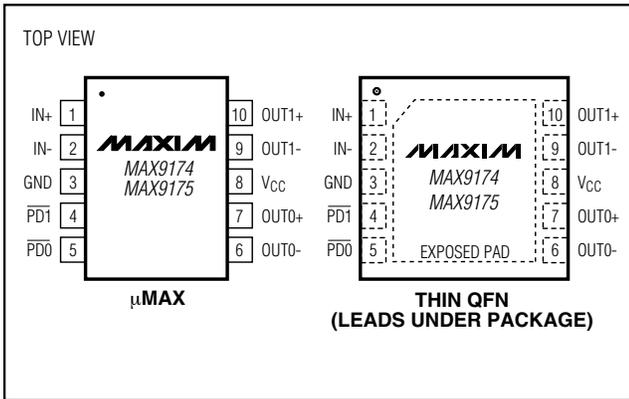
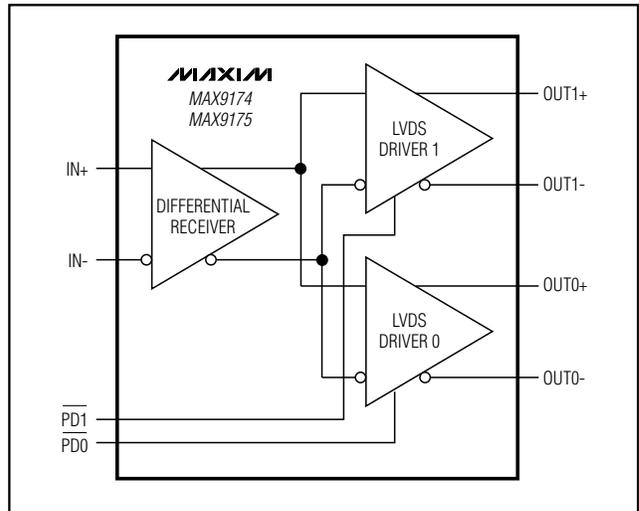


Figure 10. Human Body ESD Test Model

## Pin Configurations



## Functional Diagram



## Chip Information

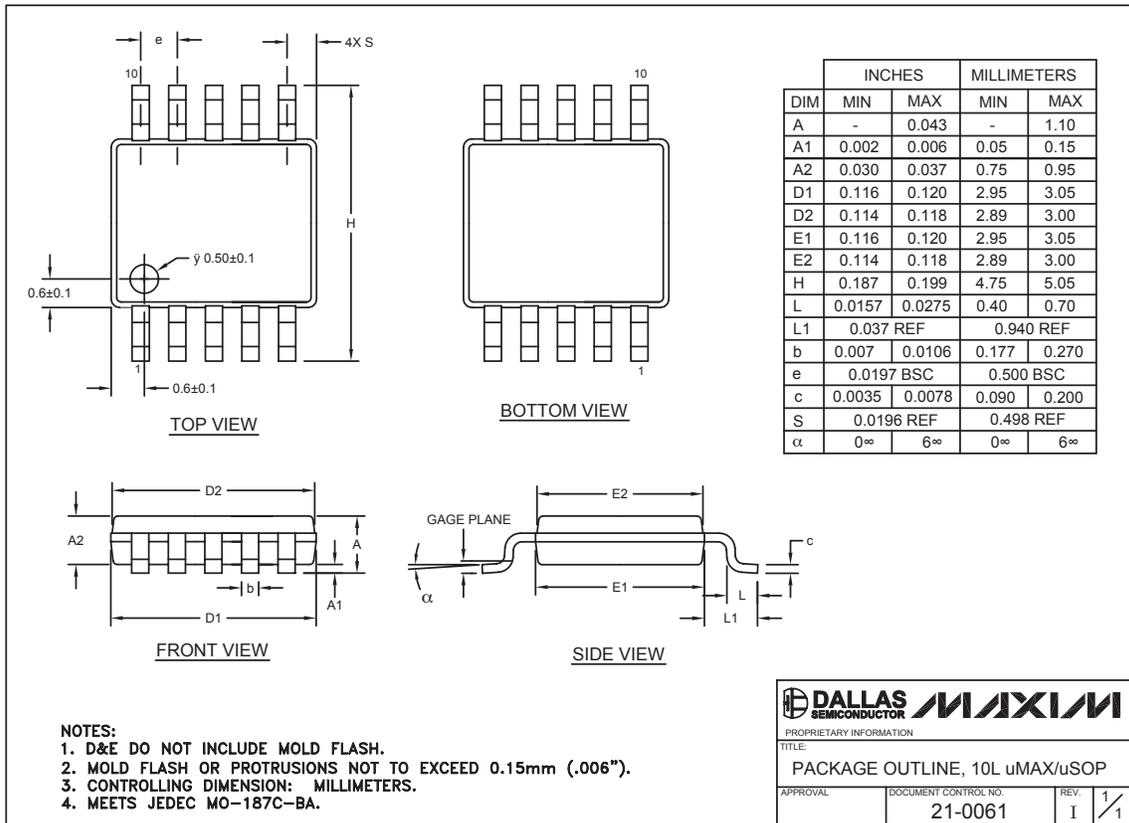
TRANSISTOR COUNT: 693  
PROCESS: CMOS

# 670MHz LVDS-to-LVDS and Anything-to-LVDS 1:2 Splitters

## Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).)

MAX9174/MAX9175

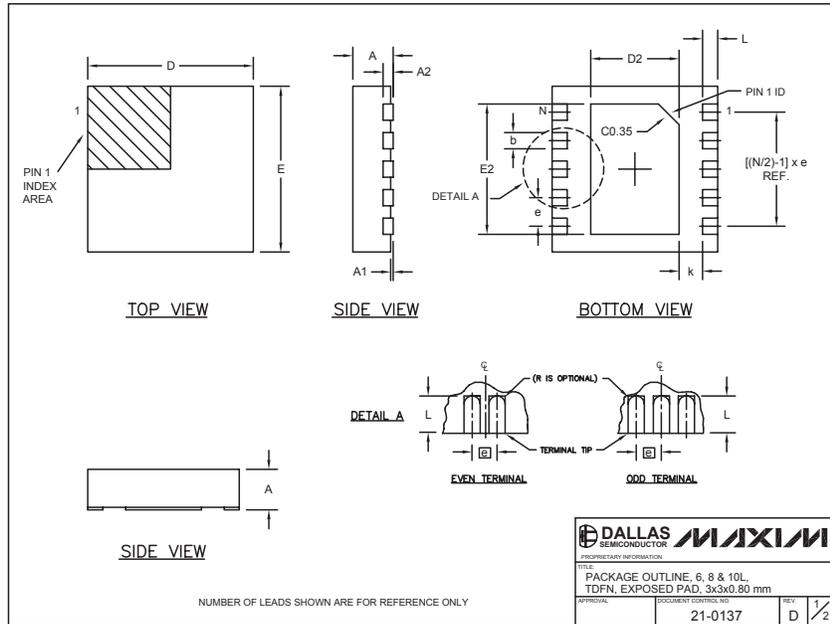


10L uMAX/EPs

# 670MHz LVDS-to-LVDS and Anything-to-LVDS 1:2 Splitters

## Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).)



6, 8, & 10L, DFN THINLEPS

COMMON DIMENSIONS							
SYMBOL	MIN.	MAX.					
A	0.70	0.80					
D	2.90	3.10					
E	2.90	3.10					
A1	0.00	0.05					
L	0.20	0.40					
k	0.25 MIN.						
A2	0.20 REF.						

PACKAGE VARIATIONS							
PKG. CODE	N	D2	E2	e	JEDEC SPEC	b	[(N/2)-1] x e
T633-1	6	1.50±0.10	2.30±0.10	0.95 BSC	MO229 / WEEA	0.40±0.05	1.90 REF
T833-1	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF
T1033-1	10	1.50±0.10	2.30±0.10	0.50 BSC	MO229 / WEED-3	0.25±0.05	2.00 REF

NOTES:  
 1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.  
 2. COPLANARITY SHALL NOT EXCEED 0.08 mm.  
 3. WARPAGE SHALL NOT EXCEED 0.10 mm.  
 4. PACKAGE LENGTH/PACKAGE WIDTH ARE CONSIDERED AS SPECIAL CHARACTERISTIC(S).  
 5. DRAWING CONFORMS TO JEDEC MO229, EXCEPT DIMENSIONS "D2" AND "E2".  
 6. "N" IS THE TOTAL NUMBER OF LEADS.

<b>DALLAS SEMICONDUCTOR</b>	<b>MAXIM</b>
<small>PROPRIETARY INFORMATION</small>	
TITLE: PACKAGE OUTLINE, 6, 8 & 10L, TDFN, EXPOSED PAD, 3x3x0.80 mm	
<small>APPROVAL</small>	<small>DOCUMENT CONTROL NO.</small>
21-0137	REV D 2/2

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